

PULSE-WIDTH-MODULATION CONTROL CIRCUITS

Description

The AZ7500B is a voltage mode pulse width modulation switching regulator control circuit designed primarily for power supply control.

The AZ7500B consists of a reference voltage circuit, two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, and an output control circuit. The precision of voltage reference (V_{REF}) is improved up to $\pm 1\%$ through trimming and this provides a better output voltage regulation. The AZ7500B provides for push-pull or single-ended output operation, which can be selected through the output control.

The difference between AZ7500B and AZ7500C is that they have 4.95V and 5V reference voltage respectively.

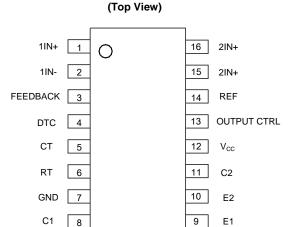
The AZ7500B is available in standard packages of SO-16.

Features

Notes:

- Stable 4.95V Reference Voltage Trimmed to ±1.0% Accuracy
- Uncommitted Output TR for 200mA Sink or Source Current
- Single-End or Push-Pull Operation Selected by Output Control
- Internal Circuitry Prohibits Double Pulse at Either Output
- Complete PWM Control Circuit with Variable Duty Cycle
- On-Chip Oscillator with Master or Slave Operation
- Totally Lead-Free; RoHS Compliant (Notes 1 & 2)

Pin Assignments



SO-16

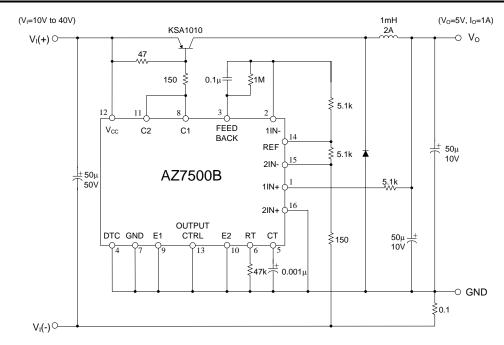
Applications

- SMPS
- Back Light Inverter
- Charger

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Typical Applications Circuit



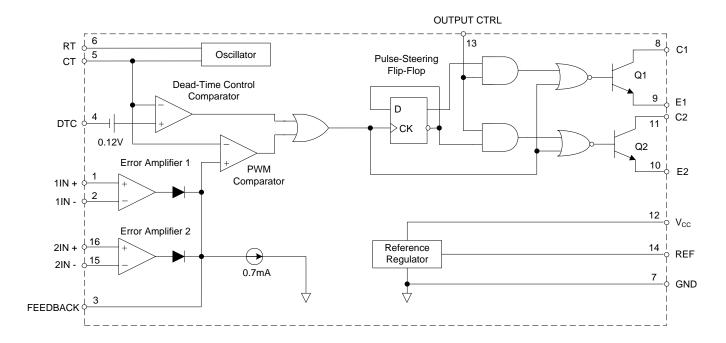
Pulse Width Modulated Step-down Converter



Output Function Table

Signal for Output Control Output Function			
$V_{I} = GND$	Single-ended or parallel output		
$V_{I} = V_{REF}$	Normal push-pull operation		

Functional Block Diagram





Absolute Maximum Ratings (Note 3)

Symbol	Parameter	Rating	Unit
V _{CC}	Supply Voltage (Note 4)	40	V
Vı	Amplifier Input Voltage	-0.3 to V _{CC} + 0.3	V
Vo	Collector Output Voltage	40	V
Io	Collector Output Current	250	mA
R _{θJA}	Package Thermal Impedance (Note 5)	73	°C/W
-	Lead Temperature 1.6mm from case for 10 seconds	+260	°C
T _{STG}	Storage Temperature Range	-65 to +150	°C
- ESD Rating (Machine Model)		200	V

Notes: 3. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
V _{cc}	Supply Voltage	7	15	36	V
V _{C1} , V _{C2}	Collector Output Voltage	-	30	36	V
I _{C1} , I _{C2}	Collector Output Current (Each Transistor)	-	-	200	mA
V_1	Amplifier Input Voltage	0.3	-	V _{CC} -2	V
I _{FB}	I _{FB} Current Into Feedback Terminal I _{REF} Reference Output Current C _T Timing Capacitor R _T Timing Resistor f _{OSC} Oscillator Frequency - PWM Input Voltage (Pin 3, 4, 14)		_	0.3	mA
I _{REF}			_	10	mA
Ст			0.001	10	μF
R _T			30	500	kΩ
f _{osc}			40	200	kHz
_			-	5.3	V
T _A	Operating Free-Air Temperature	-40	_	+85	°C

^{4.} All voltage values are with respect to the network ground terminal.

^{5.} Maximum power dissipation is a function of $T_J(max)$, $R_{\theta JA}$ and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/R_{\theta JA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.

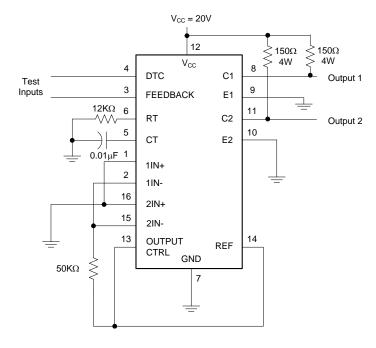


Electrical Characteristics (@V_{CC}=20V, T_A= +25°C, f=10kHz, unless otherwise specified.)

Symbol	Paran	neters	Conditions	Min	Тур	Max	Unit	
Reference Se	ection			1	, Ji			
			I _{REF} =1mA	4.90	4.95	5.0	V	
V_{REF}	Output Reference Voltage		I _{REF} =1mA, T _A = -40 to +85°C	4.85	4.95	5.05	V	
R _{LINE}	Line Regulation		V _{CC} = 7V to 36V	_	2	25	mV	
R _{LOAD}	Load Regulation		I _{REF} =1mA to 10mA	_	1	15	mV	
I _{sc}	Short-Circuit Output Cur	rent	V _{REF} = 0V	10	35	50	mA	
Oscillator Se	ection			•	•	•	•	
			C_T =0.001 μ F, R_T =30 $K\Omega$	_	40	_		
f _{osc}	Oscillator Frequency		$C_T=0.01\mu F, R_T=12K\Omega$	9.2	10	10.8	kHz	
1030	Community		$C_T=0.01\mu F, R_T=12K\Omega,$ $T_A=-40 \text{ to } +85^{\circ}C$	9.0	-	12		
Δf /ΔΤ	Frequency Change with	Temperature	$C_T=0.01\mu F, R_T=12K\Omega,$ $T_A=-40 \text{ to } +85^{\circ}C$	_	_	1	%	
Dead-Time C	Control Section							
I _{BIAS}	Input Bias Current		V _{CC} =15V, V4= 0 to 5.25V	_	-2	-10	μΑ	
D(MAX)	Maximum Duty Cycle		V _{CC} =15V, V4= 0V, Pin 13= V _{REF}	45	-	-	%	
$V_{\rm ITH}$	Input Threshold Voltage		Zero Duty Cycle	_	3	3.3	V	
VITH Input Threshold Voltage			Maximum Duty Cycle	0	-	_	v	
Error-Amplif	ier Section				T	T		
V_{IO}	Input Offset Voltage		V3 = 2.5V	_	2	10	mV	
I _{IO}	Input Offset Current		V3 = 2.5V	_	25	250	nA	
I _{BIAS}	Input Bias Current		V3 = 2.5V	_	0.2	1	μΑ	
V _{CM}	Common-Mode Input Voltage Range		V _{CC} =7V to 36V	-0.3	-	V _{CC} -2	V	
G _{VO}	Open-Loop Voltage Gain		$V_0 = 0.5V$ to 3.5V	70	95	_	dB	
BW	Unity-Gain Bandwidth		-	_	650	_	kHz	
CMRR	Common-Mode Rejectio	n Ratio	-	65	80	_	dB	
I _{SINK}	Output Sink Current (Fe	edback)	$V_{ID} = -15 \text{mV to } -5 \text{V}, \text{ V3} = 0.7 \text{V}$	-0.3	-0.7	_	mA	
I _{SOURCE}	Output Source Current	(Feedback)	V_{ID} =15mV to 5V, V3 = 3.5V	2	_	_	mA	
PWM Compa	rator Section			1	T	T		
V_{ITH}	Input Threshold Voltage		Zero duty cycle	_	4	4.5	V	
I _{SINK}	Input Sink Current		V3 = 0.7V	-0.3	-0.7	_	mA	
Output Secti	on			1	T	T		
V _{CE} (SAT)	Output Saturation	Common Emitter	$V_E = 0V, I_C = 200mA$	_	1.1	1.3	. ,,	
V _{CC} (SAT)	Voltage Emitter Follower		$V_{CC} = 15V$, $I_E = -200$ mA	-	1.5	2.5	V	
I _C (OFF)	Collector Off-State Current		$V_{CE} = 36V, V_{CC} = 36V$	_	2	100	μΑ	
I _E (OFF)	Emitter Off-State Curren	t	$V_{CC} = V_C = 36V, V_E = 0$	_	_	-100	μΑ	
Total Device	T			1	.	.	1	
I _{cc}	Supply Current		Pin 6 = V_{REF} , V_{CC} =15 V	-	6	10	mA	
Output Switch	ching Characteristics			1	1	1	1	
t _R	Rise Time		Common Emitter Common Collector	_	100	200	ns	
t _F	Fall Time		Common Emitter Common Collector	_	25	100	ns	



Parameter Measurement Information



Test Circuit

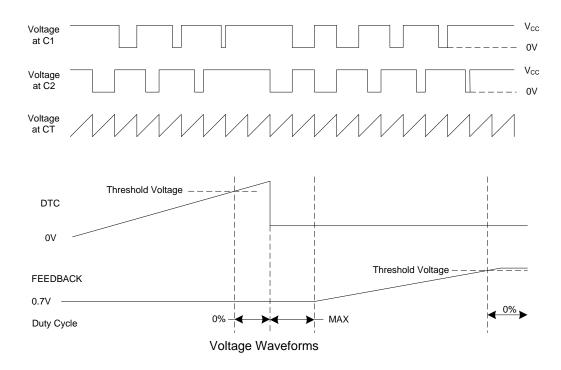


Figure 1. Operational Test Circuit and Waveforms

July 2015

© Diodes Incorporated



Parameter Measurement Information (Cont.)

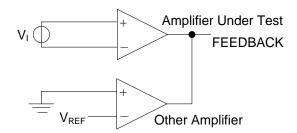
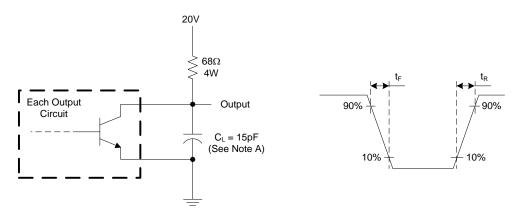
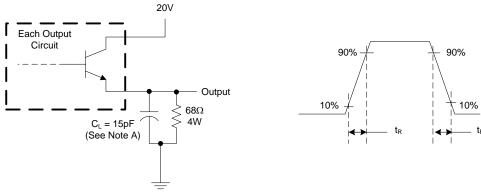


Figure 2. Error Amplifier Characteristics



Note A: C_L includes probe and jig capacitance.

Figure 3. Common-Emitter Configuration



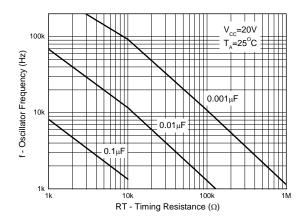
Note A: C_L includes probe and jig capacitance.

Figure 4. Emitter-Follower Configuration

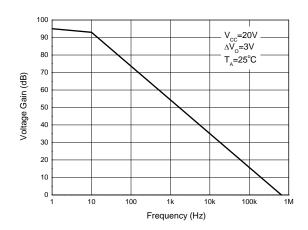


Performance Characteristics

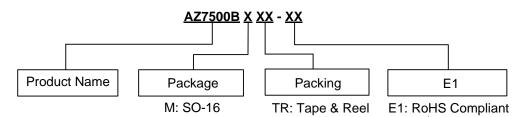
Oscillator Frequency vs. RT and CT



Error Amplifier Small-Signal Voltage Gain vs. Frequency



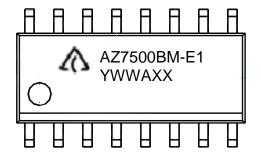
Ordering Information



Package	kage Temperature Range Part Number		Marking ID	Packing	
SO-16	-40 to +85°C	AZ7500BMTR-E1	AZ7500BM-E1	4000/Tape and Reel	

Marking Information

(Top View)



First Line: Logo and Marking ID (See Ordering Information)
Second Line: Date Code

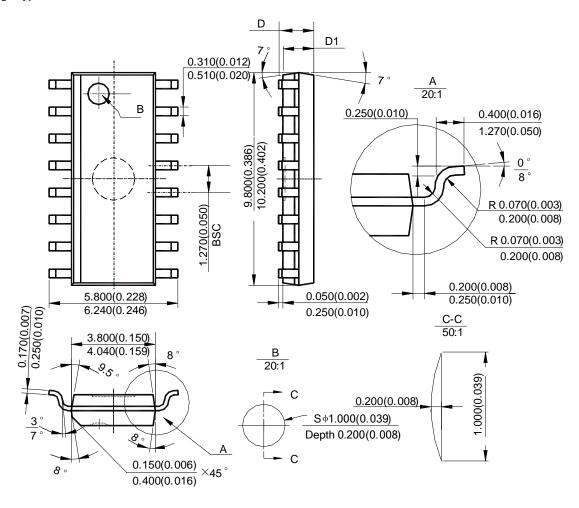
Y: Year

WW: Work Week of Molding A: Assembly House Code XX: 7th and 8th Digits of Batch No.



Package Outline Dimensions (All dimensions in mm(inch).)

(1) Package Type: SO-16



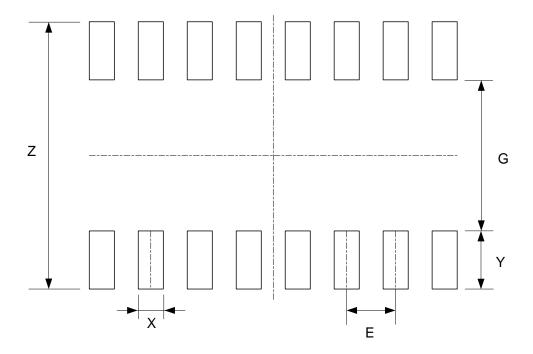
Note: Eject hole, oriented hole and mold mark is optional.

Symbol	Symbol		D			D1			
	min(mm)	max(mm)	min(inch)	max(inch)	min(mm)	max(mm)	min(inch)	max(inch)	
	Option1	1.350	1.750	0.053	0.069	1.250	1.650	0.049	0.065
	Option2	-	1.260	-	0.050	1.020	-	0.040	-



Suggested Pad Layout

(1) Package Type: SO-16



Dimensions	Z	G (see als)	X (22.22) (((2.24)	Y	E (22.22) (((2.24))
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050

July 2015



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO. THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein, neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com